

FORM PTO-1449		<div style="border: 1px solid black; border-radius: 50%; padding: 5px; display: inline-block;"> E 3577 11 28 2004 TRADEMARK OFFICE </div>		ATTY. DOCKET NO. 2132.0010002		APPLICATION NO. 10/674,060	
INFORMATION DISCLOSURE STATEMENT				FIRST NAMED INVENTOR Xiangfeng Duan			
				FILING DATE September 30, 2003		ART UNIT 2812 2825	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
IA	AA1	US 2002/0130311	09/2002	Lieber et al.	—	—	—
IA	AB1	US 2002/0130353	09/2002	Lieber et al.	—	—	—
	AC1						
	AD1						
	AE1						
	AF1						
	AG1						
	AH1						
	AI1						
	AJ1						
	AK1						
FOREIGN PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
	AL1						Yes
							No
	AM1						Yes
							No
	AN1						Yes
							No
	AO1						Yes
							No
	AP1						Yes
							No
OTHER (Including Author, Title, Date, Pertinent Pages, etc.)							
IA	AR	1	Chung et al., "Silicon nanowire devices", American Institute of Physics, Vol. 76, No. 15, April 10, 2000, 5 pgs.				
IA	AS	1	Duan et al., "High-performance thin-film transistors using semiconductor nanowires and nanoribbons", Nature, Vol. 425, September 18, 2003, pgs. 274-278				
IA	AT	1	Toshishige Yamada, "Analysis of submicron carbon nanotube field-effect transistors", Applied Physics Letters, Vol. 76, No. 5, January 31, 2000, American Institute of Physics, 5 pgs.				
EXAMINER					DATE CONSIDERED		
					9/28/04		
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							



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	FIRST NAMED INVENTOR Xiangfeng Duan		
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U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
	AA2						
	AB2						
	AC2						
	AD2						
	AE2						
	AF2						
	AG2						
	AH2						
	AI2						
	AJ2						
	AK2						

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION
	AL2						Yes No
	AM2						Yes No
	AN2						Yes No
	AO2						Yes No
	AP2						Yes No

OTHER (Including Author, Title, Date, Pertinent Pages, etc.)

	AR	2	Tans et al., "Room-temperature transistor based on a single carbon nanotube", Nature, Vol. 393, May 7, 1998, 5 pgs.
	AS	2	
	AT	2	

EXAMINER 	DATE CONSIDERED 7/28/04
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.	